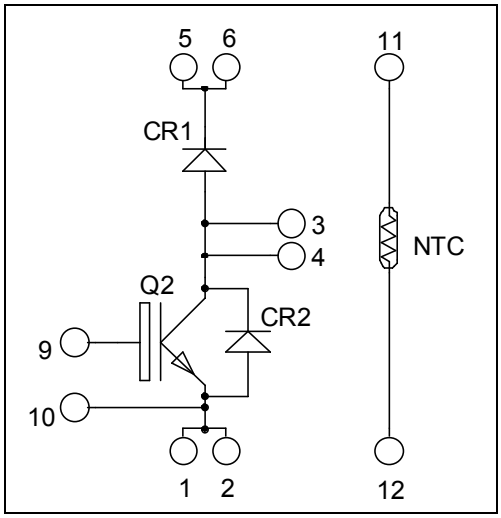
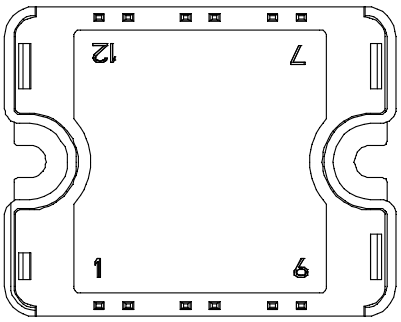
APTGTQ100DA65T1G

Boost chopper
High speed Trenchstop 5
IGBT Power Module

V_{CES} = 650V
I_C = 100A @ Tc = 25°C





Pins 1/2 ; 3/4 ; 5/6 must be shorted together

Application
- AC and DC motor control
- Switched Mode Power Supplies
- Power Factor Correction

Features
- ***Trench + Field Stop IGBT5 technology***
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 100 kHz
  - Low leakage current
- Very low stray inductance
- Internal thermistor for temperature monitoring

Benefits
- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS compliant

All ratings @ T_j = 25°C unless otherwise specified

Absolute maximum ratings

Symbol	*Parameter*		*Max ratings*	*Unit*
V_{CES}	Collector - Emitter Voltage		650	V
I_C	Continuous Collector Current	T_C = 25°C	100	A
		T_C = 80°C	60	
I_{CM}	Pulsed Collector Current	T_C = 25°C	200	
V_{GE}	Gate – Emitter Voltage		±20	V
P_D	Power Dissipation		250	W

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	V_{GE} = 0V, V_{CE} = 650V				100	µA
$V_{CE(sat)}$	Collector Emitter Saturation Voltage	V_{GE} =15V I_C = 100A	T_j = 25°C		1.65	2.2	V
			T_j = 150°C		1.9		
$V_{GE(th)}$	Gate Threshold Voltage	V_{GE} = V_{CE} , I_C = 1mA		3.3	4.0	4.7	V
I_{GES}	Gate – Emitter Leakage Current	V_{GE} = 20V, V_{CE} = 0V				240	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
C_{ies}	Input Capacitance	V_{GE} = 0V V_{CE} = 25V f = 1MHz			6000		pF
C_{oes}	Output Capacitance				100		
C_{res}	Reverse Transfer Capacitance				22		
Q_G	Gate charge	V_{GE} = 15V, I_C = 100A V_{CE} = 520V			240		nC
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C) V_{GE} = 15V V_{Bus} = 400V I_C = 50A R_G = 2Ω			21		ns
T_r	Rise Time				15		
$T_{d(off)}$	Turn-off Delay Time				180		
T_f	Fall Time				18		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (150°C) V_{GE} = 15V V_{Bus} = 400V I_C = 50A R_G = 2Ω			20		ns
T_r	Rise Time				15		
$T_{d(off)}$	Turn-off Delay Time				205		
T_f	Fall Time				26		
E_{on}	Turn on Energy	V_{GE} = 15V V_{Bus} = 400V I_C = 50A R_G = 2Ω	T_j = 150°C		1.5		mJ
E_{off}	Turn off Energy		T_j = 150°C		0.6		
R_{Gint}	Integrated gate resistor				2.5		Ω
R_{thJC}	Junction to Case Thermal Resistance					0.6	°C/W

diode ratings and characteristics (per diode)

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Peak Repetitive Reverse Voltage					650	V
I_{RM}	Reverse Leakage Current	V_R=650V				100	µA
I_F	DC Forward Current		Tc = 25°C		100		A
V_F	Diode Forward Voltage	I_F = 100A V_{GE} = 0V	T_j = 25°C		1.6	2.2	V
			T_j = 150°C		1.65		
t_{rr}	Reverse Recovery Time	I_F = 50A V_R = 400V di/dt =3000A/µs	T_j = 25°C		46		ns
			T_j = 150°C		62		
Q_{rr}	Reverse Recovery Charge		T_j = 25°C		1		µC
			T_j = 150°C		2		
R_{thJC}	Junction to Case Thermal Resistance					0.7	°C/W

Temperature sensor NTC (see application note APT0406 on www.microsemi.com).

Symbol	*Characteristic*		*Min*	*Typ*	*Max*	*Unit*
R_{25}	Resistance @ 25°C			50		kΩ
$\Delta R_{25}/R_{25}$				5		%
$B_{25/85}$	T_{25} = 298.15 K			3952		K
$\Delta B/B$		T_C=100°C		4		%

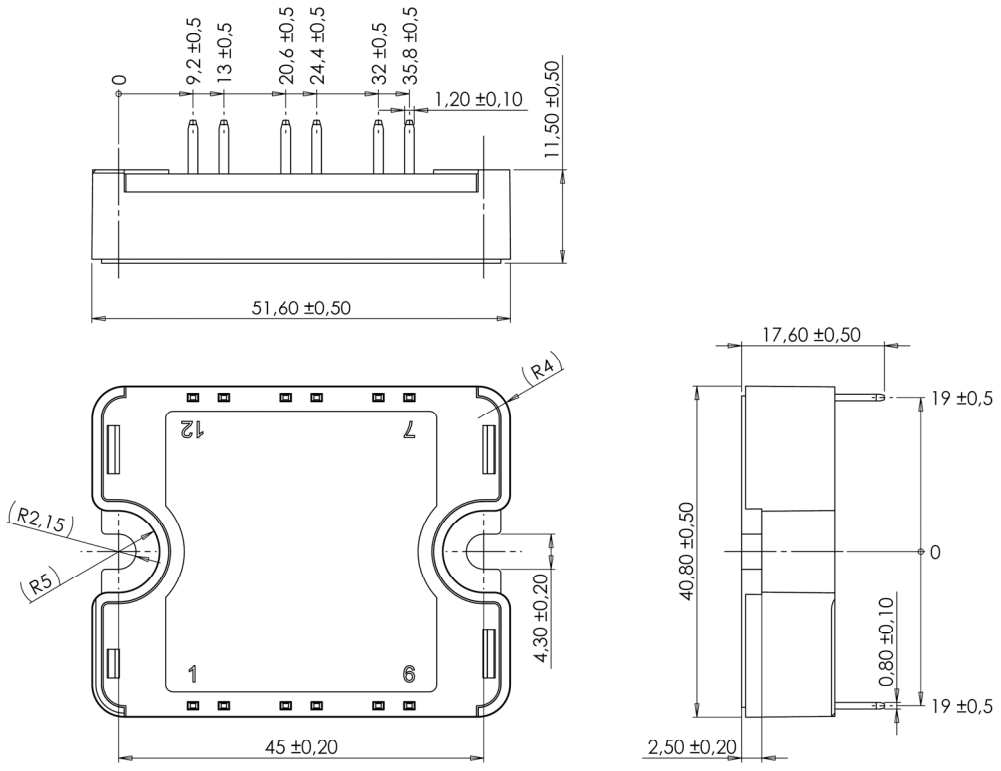
$$R_T = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$$

T: Thermistor temperature
R_T: Thermistor value at T

Thermal and package characteristics

Symbol	*Characteristic*			*Min*	*Max*	*Unit*
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000		V
T_J	Operating junction temperature range			-40	175	°C
T_{JOP}	Recommended junction temperature under switching conditions			-40	$T_J$max -25	
T_{STG}	Storage Temperature Range			-40	125	
T_C	Operating Case Temperature			-40	125	
Torque	Mounting torque	To heatsink	M4	2	3	N.m
Wt	Package Weight				80	g

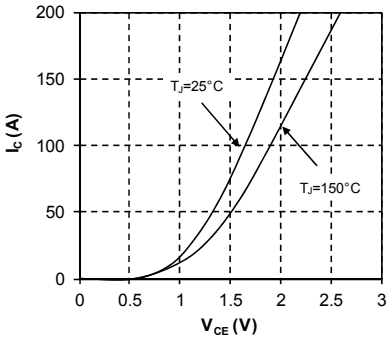
Package outline (dimensions in mm)



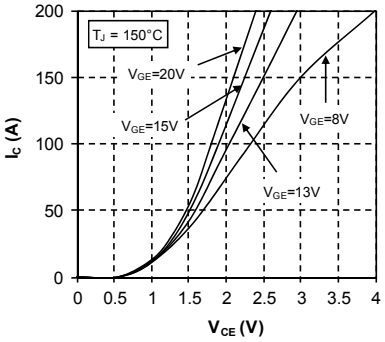
See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com

Typical performance curve

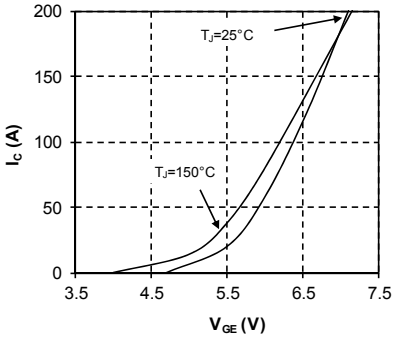
Output Characteristics (V_{GE}=15V)



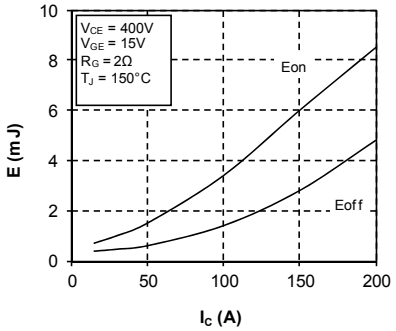
Output Characteristics



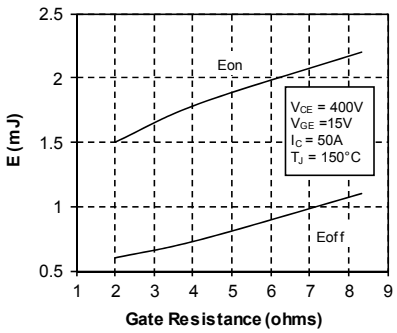
Transfert Characteristics



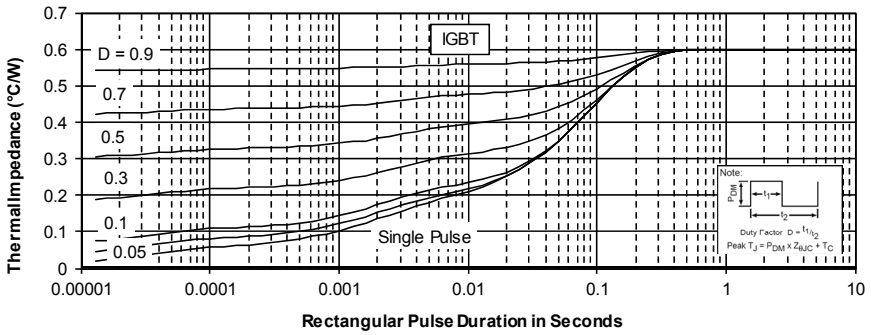
Energy losses vs Collector Current

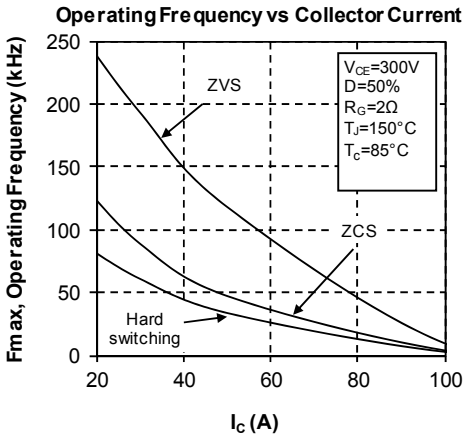


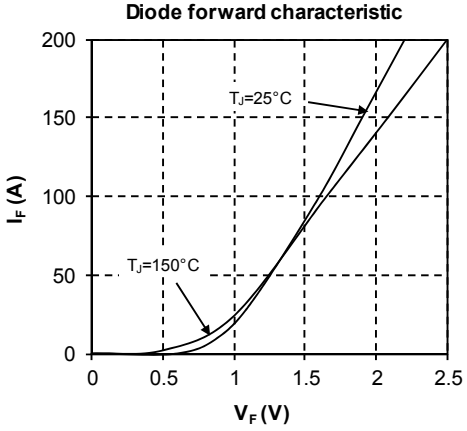
Switching Energy Losses vs Gate Resistance

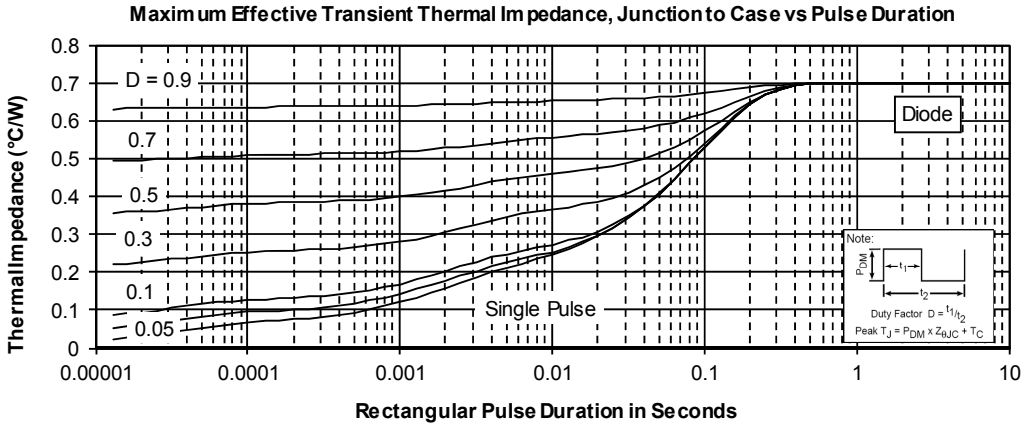


Maximum Effective Transient Thermal Impedance, Junction to Case vs Pulse Duration









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